

# MBR16100 THRU MBR16200

Schottky Diodes

### **Features**

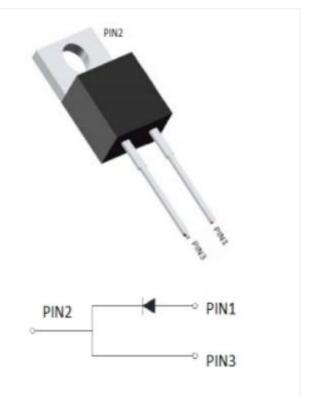
- High efficiency operation
- Guard ring for enhanced ruggedness and long term reliablity
- High purity,high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Solder dip maximum peak of 275 °C /7s, per JESD 22-B106

# **Typical Application**

For use in switching power supplies, converters, freewheeling diodes and reverse battery protection.

### **Mechanical Data**

- Package: TO-220AC
   Molding compound meets UL 94 V-0 flammability rating,RoHS-compliant
- Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- Polarity: Color Band denotes cathode end



■ Maximum Ratings (Ta=25°C Unless otherwise specified)

| DADAMETED                              |                                  |                  | 0   | MBR        |       |     |
|--|----------------------------------|------------------|---|------------|-------|-----|
| PARAMETER                              | PARAMETER Symbol Unit Conditions |                  | 16100   | 16150      | 16200 |     |
| Repetitive Peak Reverse Voltage        | V <sub>RRM</sub>                 | V                |   | 100        | 150   | 200 |
| Average Rectified Output Current       | lo                               | Α                | 60HZ Half-sine wave, Resistance load, Tc(Fig.1)                               | 16         |       |     |
| Surge(Nonrepetitive)Forward<br>Current | I <sub>FSM</sub>                 | Α                | 60HZ sine wave, 1 cycle,<br>Ta=25℃  | 250        |       |     |
| Current Squared Time                   | I <sup>2</sup> T                 | A <sup>2</sup> S | 1ms≤t < 8.3ms Tj =25°C,Rating of per diode                                    | 261        |       |     |
| Storage Temperature                    | T <sub>stg</sub>                 | $^{\circ}$       |   | -55 ~ +150 |       |     |
| Junction Temperature                   | Tj                               | $^{\circ}$ C     | IN DC Forward Mode-Forward Operations, without reverse bias, t ≤1 h (Fig. 1)① | -55 ~ +150 |       |     |

■ Electrical Characteristics (Ta=25°C Unless otherwise specified)

| PARAMETER             | Symbol            | Unit | Conditions                        |          | MBR   |       |       |  |
|-----------------------|-------------------|------|-----------------------------------|----------|-------|-------|-------|--|
| TANAMETER             | Gyillooi          |      |                                   |          | 16100 | 16150 | 16200 |  |
| Peak Forward Voltage  | $V_{FM}$          | V    | I <sub>FM</sub> =16A              |          | 0.85  | 0.9   | 0.95  |  |
| Deels Devenes Comment | I <sub>RRM1</sub> | - mA | V <sub>RM</sub> =V <sub>RRM</sub> | Ta=25℃   | 0.05  |       |       |  |
| Peak Reverse Current  | I <sub>RRM2</sub> |      |                                   | Ta=100°C | 1     |       |       |  |
| Thermal Resistance    | <b>R</b> өJ-с     | °C/W | Between junction and case         |          | 2.0   |       |       |  |

Revised: 2021-11-29

#### NOTES:

Meets the requirement of IEC 61215 Ed.2 byqass diode thermal test



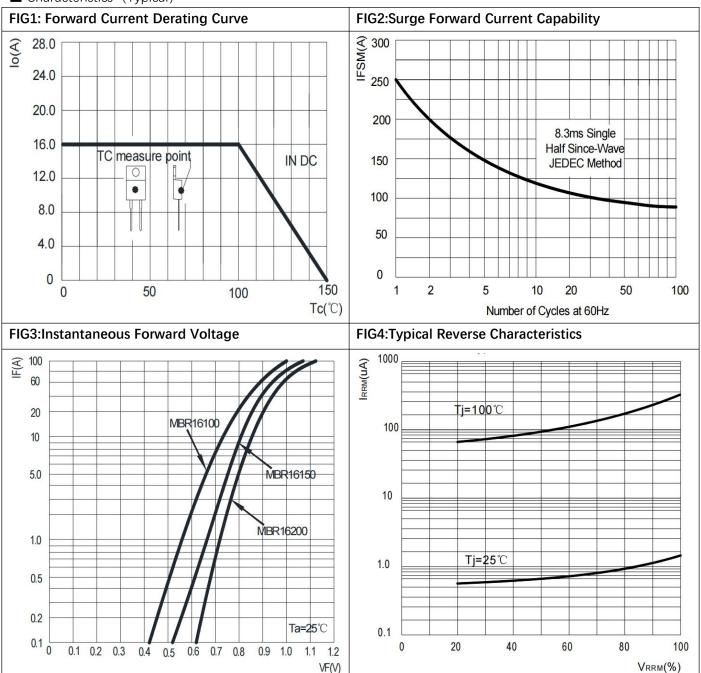




# MBR16100 THRU MBR16200

Schottky Diodes

### ■ Characteristics (Typical)



Revised: 2021-11-29







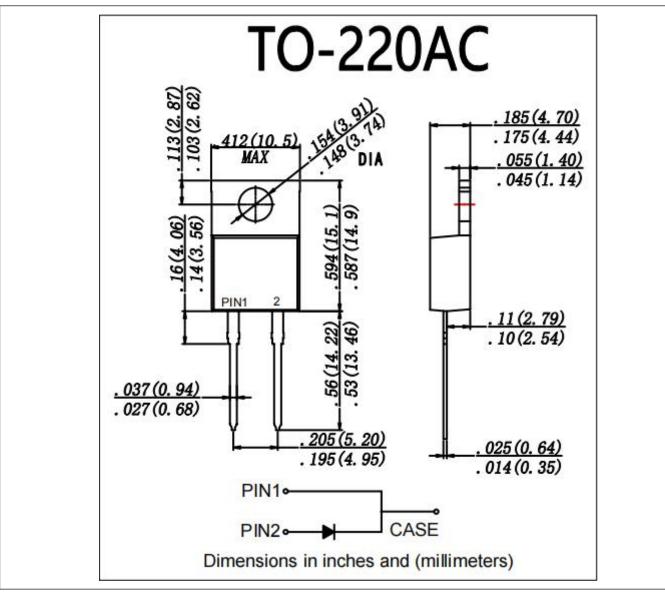
# MBR16100 THRU MBR16200

Schottky Diodes

## ■ Ordering Information (Example)

| PREFERED            | PACKAGE<br>CODE | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------------|-----------------|----------------------|-------------------------|----------------------------|---------------|
| MBR16100 ~ MBR16200 | TO-220AC        | 50                   | 1000                    | 5000                       | Tube          |

### ■ Outline Dimensions



Revised: 2021-11-29



